

L Number	Hits	Search Text	DB	Time stamp
1	2	((("5372967") or ("6236538")).PN.	USPAT; US-PGPUB	2004/05/04 09:05
2	1406967	cyлинд\$8 rod circle "semi-circle" semi near3 cycle	USPAT; US-PGPUB	2004/05/04 09:07
3	48673	inductor	USPAT; US-PGPUB	2004/05/04 09:07
4	11849	(cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor	USPAT; US-PGPUB	2004/05/04 09:09
5	399609	semiconductor	USPAT; US-PGPUB	2004/05/04 09:10
6	404672	semiconductor semiconductive	USPAT; US-PGPUB	2004/05/04 09:10
7	3107	((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:10
8	627772	(semiconductor semiconductive) substrate	USPAT; US-PGPUB	2004/05/04 09:10
9	1688	((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:10
10	573264	(semiconductor semiconductive)) and substrate groove trench	USPAT; US-PGPUB	2004/05/04 09:11
11	534	(((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:11
12	355	(semiconductor semiconductive)) and substrate) and (groove trench) ((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:33
13	855982	(semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831 insulating insulator oxide	USPAT; US-PGPUB	2004/05/04 11:24
14	30770	(groove trench) with (insulating insulator oxide)	USPAT; US-PGPUB	2004/05/04 09:21
15	75	(((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:32
16	5	(semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide))	USPAT	2004/05/04 09:26
17	4	("3305814"   "5008176"   "5112438"   "5748523"   "6303971").PN.	USPAT	2004/05/04 09:30
18	280	("3290758"   "3614554"   "5372967"   "5514832").PN. ((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:33
19	131	(semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) not ((((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide)))	USPAT; US-PGPUB	2004/05/04 09:38
20	666	inductor and ((groove trench) with (insulating insulator oxide))	USPAT; US-PGPUB	2004/05/04 09:38
21	591	(inductor and ((groove trench) with (insulating insulator oxide))) not (((((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and	USPAT; US-PGPUB	2004/05/04 09:38
		(semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) not ((((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide))) not ((((((cyлинд\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide)))		

22	149	((inductor and ((groove trench) with (insulating insulator oxide))) not ((((((cylind\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) not ((((((cylind\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide))) not ((((((cylind\$8 rod circle "semi-circle" semi near3 cycle ) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide))) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 10:13
23	33818	magnetic near4 core	USPAT; US-PGPUB	2004/05/04 10:09
24	95347	inductor inductive	USPAT; US-PGPUB	2004/05/04 11:07
25	7747	(magnetic near4 core) and (inductor inductive)	USPAT; US-PGPUB	2004/05/04 10:10
26	1741	(semiconductor semiconductive) and ((magnetic near4 core) and (inductor inductive))	USPAT; US-PGPUB	2004/05/04 10:10
27	25318	(semiconductor semiconductive) and (inductor inductive)	USPAT; US-PGPUB	2004/05/04 10:10
28	23577	((semiconductor semiconductive) and (inductor inductive)) not ((semiconductor semiconductive) and ((magnetic near4 core) and (inductor inductive)))	USPAT; US-PGPUB	2004/05/04 10:11
29	375966	core	USPAT; US-PGPUB	2004/05/04 11:23
30	23493	(insulating insulator oxide) with core	USPAT; US-PGPUB	2004/05/04 10:12
31	2156	(inductor inductive) and ((insulating insulator oxide) with core)	USPAT; US-PGPUB	2004/05/04 10:12
32	494	(semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))	USPAT; US-PGPUB	2004/05/04 10:28
33	177	((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 10:29
34	3650	(semiconductor semiconductive) and ((insulating insulator oxide) with core)	USPAT; US-PGPUB	2004/05/04 10:29
35	396677	coil	USPAT; US-PGPUB	2004/05/04 10:29
36	920	((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil	USPAT; US-PGPUB	2004/05/04 10:29
37	393	((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:19
38	265	((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil and @ad<19971119 not (((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119)	USPAT; US-PGPUB	2004/05/04 10:30
39	103	substrate and (((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil) and @ad<19971119 not (((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119))	USPAT; US-PGPUB	2004/05/04 11:06
40	62585	polysilicon	USPAT; US-PGPUB	2004/05/04 11:38
41	454129	inductor inductive coil	USPAT; US-PGPUB	2004/05/04 11:38
42	4231	polysilicon and (inductor inductive coil)	USPAT; US-PGPUB	2004/05/04 11:07
43	1276	(polysilicon and (inductor inductive coil)) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:08
44	17	((insulating insulator oxide) with core) and ((polysilicon and (inductor inductive coil)) and @ad<19971119)	USPAT; US-PGPUB	2004/05/04 11:17
45	796328	oxid\$6	USPAT; US-PGPUB	2004/05/04 11:36
46	71504	(inductor inductive coil) and oxid\$6	USPAT; US-PGPUB	2004/05/04 11:18
47	40416	((inductor inductive coil) and oxid\$6) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:25

48	1022	polysilicon and (((inductor inductive coil) and oxid\$6) and @ad<19971119)	USPAT; US-PGPUB	2004/05/04 11:19
49	16	((insulating insulator oxide) with core) and (polysilicon and (((inductor inductive coil) and oxid\$6) and @ad<19971119))	USPAT; US-PGPUB	2004/05/04 11:20
50	234540	inductor inductive coil	EPO; JPO; IBM_TDB	2004/05/04 11:29
51	211236	core	EPO; JPO; IBM_TDB	2004/05/04 11:28
52	479495	insulating insulator oxide	EPO; JPO; IBM_TDB	2004/05/04 11:28
53	5126	(inductor inductive coil) and core and (insulating insulator oxide)	EPO; JPO; IBM_TDB	2004/05/04 11:26
54	2634	(inductor inductive coil) with core with (insulating insulator oxide)	EPO; JPO; IBM_TDB	2004/05/04 11:24
55	0	((inductor inductive coil) with core with (insulating insulator oxide)) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:50
56	13068	polysilicon	JPO; IBM_TDB	2004/05/04 11:27
57	1	((inductor inductive coil) with core with (insulating insulator oxide)) and polysilicon	JPO; IBM_TDB	2004/05/04 11:27
58	1	((inductor inductive coil) and core and (insulating insulator oxide)) and polysilicon	EPO; JPO; IBM_TDB	2004/05/04 11:27
59	14448	polysilicon	EPO; JPO; IBM_TDB	2004/05/04 11:30
60	1	((inductor inductive coil) with core with (insulating insulator oxide)) and polysilicon	JPO; IBM_TDB	2004/05/04 11:27
61	290275	core	DERWENT	2004/05/04 11:28
62	714947	insulating insulator oxide	DERWENT	2004/05/04 11:28
63	300876	inductor inductive coil	DERWENT	2004/05/04 11:29
64	2489	core same (insulating insulator oxide) same (inductor inductive coil)	DERWENT	2004/05/04 11:29
65	1547	core with (insulating insulator oxide) with (inductor inductive coil)	DERWENT	2004/05/04 11:29
66	16371	polysilicon	DERWENT	2004/05/04 11:30
67	2	(core with (insulating insulator oxide) with (inductor inductive coil)) and polysilicon	DERWENT	2004/05/04 11:32
68	1	("6015742").PN.	USPAT; US-PGPUB	2004/05/04 11:32
69	8	("3988764"   "5372967"   "5514832"   "5767563"   "5770509"   "5825092"   "5900764"   "5917244").PN.	USPAT	2004/05/04 11:32
70	238208	oxidi\$5	USPAT; US-PGPUB	2004/05/04 11:36
71	0	polysilicon with oxidi\$5	USPAT; US-PGPUB	2004/05/04 11:36
72	4081	polysilicon with oxidi\$5	USPAT; US-PGPUB	2004/05/04 11:38
73	149	(inductor inductive coil) and (polysilicon with oxidi\$5)	USPAT; US-PGPUB	2004/05/04 11:39
74	56	((inductor inductive coil) and (polysilicon with oxidi\$5)) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:51